

20V N-Channel Enhancement Mode MOSFET

Voltage 20 V Current 8 A

Features

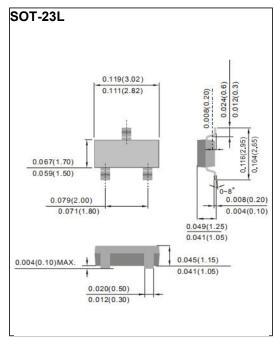
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@8A<11m\Omega$
- R_{DS(ON)}, V_{GS}@4.5V, I_D@6A<15mΩ
- Advanced Trench Process Technology
- High density cell design for ultralow on-resistance

Mechanical Data

• Case: S0T23L Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0004ounces, 0.0085 grams



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Maximum Ratings and Thermal Characteristics (T_A=25 C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 12		
Continuous Drain Current	T _C =25°C	- I _D	8		
	T _C =100°C		6	А	
Pulsed Drain Current(Note 1)	T _C =25°C	I _{DM}	16		
Power Dissipation	T _C =25°C	. P _D	1.5	W	
	Derate above 25°C		12		
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)				°C/W	
Typical Management	Junction to Ambient	$R_{\theta JA}$	80		

Limited only By Maximum Junction Temperature



Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V,I _D =250uA	20	ı	-	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	V _{DS} =V _{GS} ,I _D =250uA	1.0	1.75	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =8A	-	8.5	11	mΩ
		V _{GS} =4.5V,I _D =6A	-	11.5	15	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 12V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V _{DS} =20V, I _D =10A, V _{GS} =4.5V (Note 2,3)	-	10	-	nC
Gate-Source Charge	Q_{gs}		-	3.5	-	
Gate-Drain Charge	Q_{gd}		-	3.6	-	
Input Capacitance	Ciss	V _{DS} =20V, V _{GS} =0V,	-	1040	-	pF
Output Capacitance	Coss		-	117	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	84	-	
Turn-On Delay Time	td _(on)	$V_{DS}\text{=}20\text{V, }I_{D}\text{=}1\text{A,}$ $V_{GS}\text{=}10\text{V, }R_{G}\text{=}6\Omega$ (Note 2,3)	-	9.4	-	
Turn-On Rise Time	t _r		-	19	-	ns
Turn-Off Delay Time	td _(off)		-	66	-	
Turn-Off Fall Time	t _f		-	67	-	
Drain-Source Diode						
Maximum Continuous Drain-Source				-	42	А
Diode Forward Current	Is		-			
Diode Forward Voltage	V _{SD}	I _S =1A,V _{GS} =0V	_	0.7	1	V

NOTES:

- 1. Pulse width < 300 us, Duty cycle < 2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

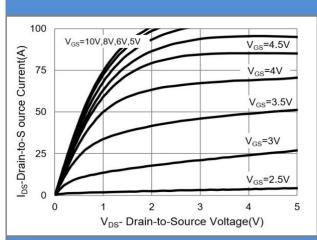


Fig.1 On-Region Characteristics

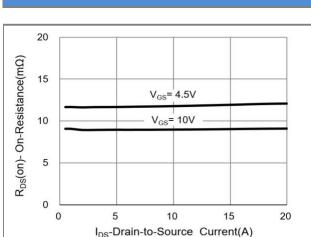


Fig.3 On-Resistance vs. Drain Current

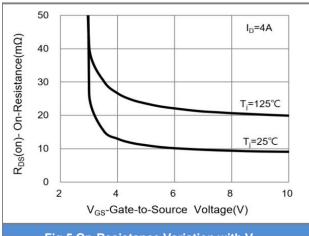


Fig.5 On-Resistance Variation with V_{GS}

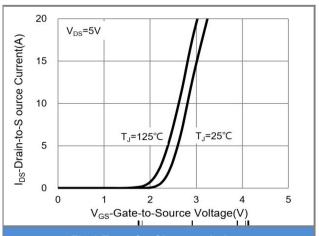


Fig.2 Transfer Characteristics

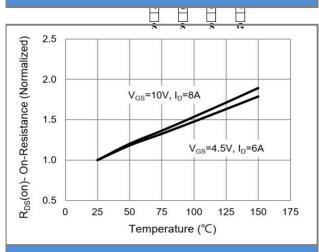


Fig.4 On-Resistance vs. Junction temperature

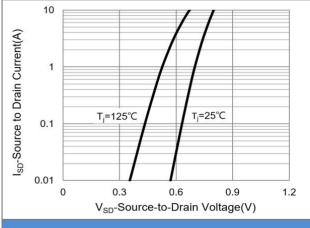


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

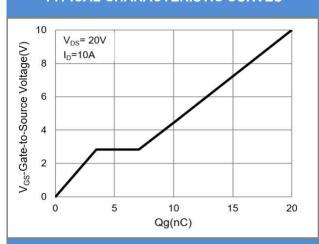
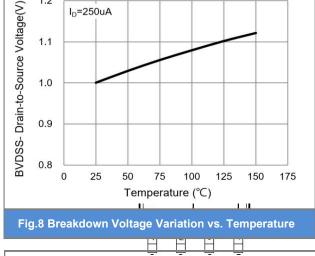


Fig.7 Gate-Charge Characteristics



1.2

I_D=250uA

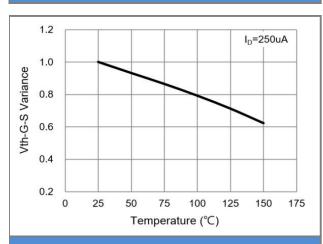


Fig.9 Threshold Voltage Variation with Temperature

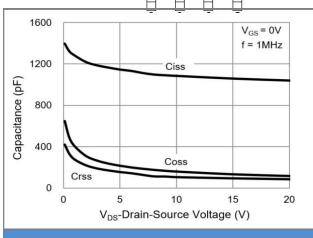


Fig.10 Capacitance vs. Drain-Source Voltage

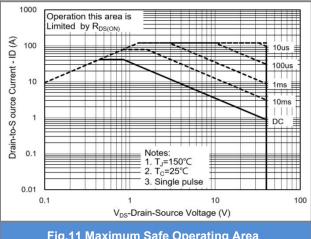


Fig.11 Maximum Safe Operating Area

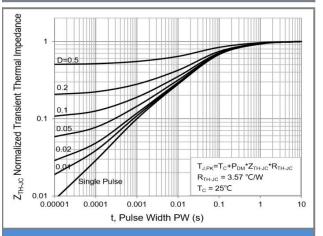


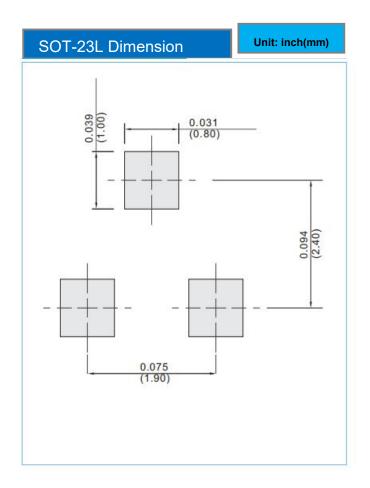
Fig.12 Normalized Transient Thermal Impedance



Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type
CSM2316S23	SOT-23L	3K pcs / 13" reel

Packaging Information & Mounting Pad Layout





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